TEXAS INSTRUMENTS

Data sheet acquired from Harris Semiconductor SCHS221D

CD54HC40103, CD74HC40103, CD74HCT40103

November 1997 - Revised October 2003

Features

- Synchronous or Asynchronous Preset
- Cascadable in Synchronous or Ripple Mode
- Fanout (Over Temperature Range)
 - Standard Outputs..... 10 LSTTL Loads
- Bus Driver Outputs 15 LSTTL Loads
- Wide Operating Temperature Range -55°C to 125°C
- Balanced Propagation Delay and Transition Times
- Significant Power Reduction Compared to LSTTL Logic ICs
- HC Types
 - 2V to 6V Operation
 - High Noise Immunity: N_{IL} = 30%, N_{IH} = 30% of V_{CC} at V_{CC} = 5V
- HCT Types
 - 4.5V to 5.5V Operation
 - Direct LSTTL Input Logic Compatibility, V_{IL}= 0.8V (Max), V_{IH} = 2V (Min)
 - CMOS Input Compatibility, I_I \leq 1µA at V_{OL}, V_{OH}

Ordering Information

PART NUMBER	TEMP. RANGE (^o C)	PACKAGE
CD54HC40103F3A	-55 to 125	16 Ld CERDIP
CD74HC40103E	-55 to 125	16 Ld PDIP
CD74HC40103M	-55 to 125	16 Ld SOIC
CD74HC40103MT	-55 to 125	16 Ld SOIC
CD74HC40103M96	-55 to 125	16 Ld SOIC
CD74HCT40103E	-55 to 125	16 Ld PDIP
CD74HCT40103M	-55 to 125	16 Ld SOIC
CD74HCT40103MT	-55 to 125	16 Ld SOIC
CD74HCT40103M96	-55 to 125	16 Ld SOIC

NOTE: When ordering, use the entire part number. The suffix 96 denotes tape and reel. The suffix T denotes a small-quantity reel of 250.

High-Speed CMOS Logic 8-Stage Synchronous Down Counters

Description

The 'HC40103 and CD74HCT40103 are manufactured with high speed silicon gate technology and consist of an 8-stage synchronous down counter with a single output which is active when the internal count is zero. The 40103 contains a single 8-bit binary counter. Each has control inputs for enabling or disabling the clock, for clearing the counter to its maximum count, and for presetting the counter either synchronously or asynchronously. All control inputs and the \overline{TC} output are active-low logic.

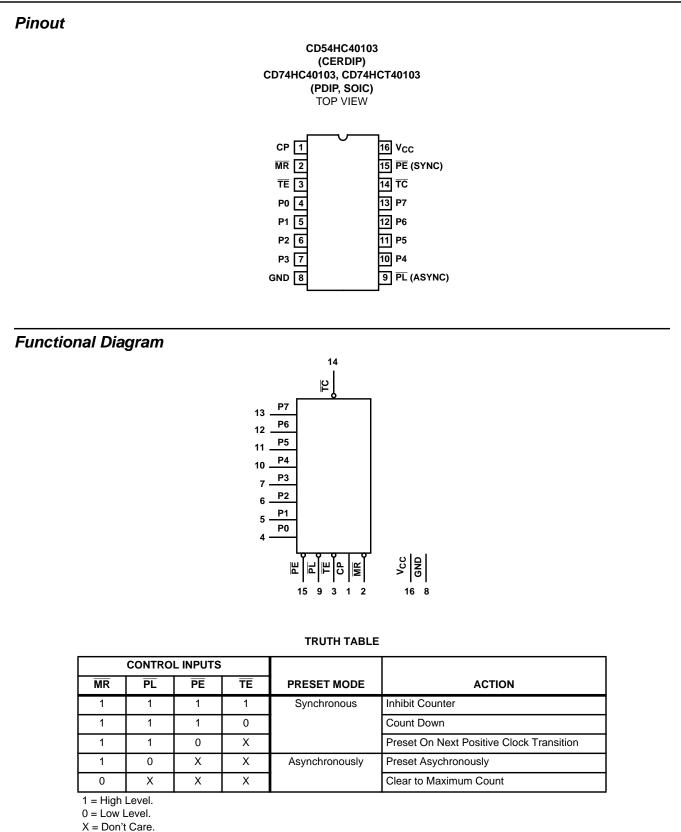
In normal operation, the counter is decremented by one count on each positive transition of the CLOCK (CP). Counting is inhibited when the \overline{TE} input is high. The \overline{TC} output goes low when the count reaches zero if the \overline{TE} input is low, and remains low for one full clock period.

When the \overline{PE} input is low, data at the P0-P7 inputs are clocked into the counter on the next positive clock transition regardless of the state of the \overline{TE} input. When the \overline{PL} input is low, data at the P0-P7 inputs are asynchronously forced into the counter regardless of the state of the \overline{PE} , \overline{TE} , or CLOCK inputs. Input P0-P7 represent a single 8-bit binary word for the 40103. When the MR input is low, the counter is asynchronously cleared to its maximum count of 255_{10} , regardless of the state of any other input. The precedence relationship between control inputs is indicated in the truth table.

If all control inputs except $\overline{\text{TE}}$ are high at the time of zero count, the counters will jump to the maximum count, giving a counting sequence of 100_{16} or 256_{10} clock pulses long.

The 40103 may be cascaded using the $\overline{\text{TE}}$ input and the $\overline{\text{TC}}$ output, in either a synchronous or ripple mode. These circuits possess the low power consumption usually associated with CMOS circuitry, yet have speeds comparable to low power Schottky TTL circuits and can drive up to 10 LSTTL loads.

CAUTION: These devices are sensitive to electrostatic discharge. Users should follow proper IC Handling Procedures. Copyright © 2003, Texas Instruments Incorporated



Clock connected to clock input.

Synchronous Operation: changes occur on negative-to-positive clock transitions.

Load Inputs: MSB = P7, LSB = P0.

Absolute Maximum Ratings

DC Supply Voltage, V _{CC} 0.5V to 7V
DC Input Diode Current, IIK
For V _I < -0.5V or V _I > V _{CC} + 0.5V±20mA
DC Output Diode Current, IOK
For $V_0 < -0.5V$ or $V_0 > V_{CC} + 0.5V$
DC Output Source or Sink Current per Output Pin, IO
For $V_{O} > -0.5V$ or $V_{O} < V_{CC} + 0.5V$ ±25mA
DC V _{CC} or Ground Current, I _{CC} ±50mA

Operating Conditions

Temperature Range, T _A 55°C to 125°C
Supply Voltage Range, V _{CC}
HC Types
HCT Types4.5V to 5.5V
DC Input or Output Voltage, V _I , V _O 0V to V _{CC}
Input Rise and Fall Time
2V
4.5V 500ns (Max)
6V

Thermal Information

Thermal Resistance (Typical, Note 1)	θ _{JA} (^o C/W)
E (PDIP) Package	
M (SOIC) Package	73
Maximum Junction Temperature	
Maximum Storage Temperature Range	65 ⁰ C to 150 ⁰ C
Maximum Lead Temperature (Soldering 10s)	
(SOIC - Lead Tips Only)	

CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

NOTE:

1. The package thermal impedance is calculated in accordance with JESD 51-7.

DC Electrical Specifications

		TE: CONDI		v _{cc}		25 ⁰ C		-40 ⁰ C 1	O 85°C	-55°C TO 125°C		4
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES					-		_	-				-
High Level Input	VIH	-	-	2	1.5	-	-	1.5	-	1.5	-	V
Voltage				4.5	3.15	-	-	3.15	-	3.15	-	V
				6	4.2	-	-	4.2	-	4.2	-	V
Low Level Input	VIL	-	-	2	-	-	0.5	-	0.5	-	0.5	V
Voltage				4.5	-	-	1.35	-	1.35	-	1.35	V
				6	-	-	1.8	-	1.8	-	1.8	V
High Level Output V _{OH} Voltage CMOS Loads	VOH	V _{IH} or V _{IL}	-0.02	2	1.9	-	-	1.9	-	1.9	-	V
			-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
			-0.02	6	5.9	-	-	5.9	-	5.9	-	V
High Level Output			-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
			-5.2	6	5.48	-	-	5.34	-	5.2	-	V
Low Level Output	VOL	V _{IH} or V _{IL}	0.02	2	-	-	0.1	-	0.1	-	0.1	V
Voltage CMOS Loads			0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
			0.02	6	-	-	0.1	-	0.1	-	0.1	V
Low Level Output			-	-	-	-	-	-	-	-	-	V
Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
			5.2	6	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V _{CC} or GND	-	6	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V _{CC} or GND	0	6	-	-	8	-	80	-	160	μA

		TEST CONDITIONS		Vcc	25 ⁰ C			-40°C TO 85°C		-55°C TO 125°C		
PARAMETER	SYMBOL	V _I (V)	I _O (mA)	(V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HCT TYPES												
High Level Input Voltage	VIH	-	-	4.5 to 5.5	2	-	-	2	-	2	-	V
Low Level Input Voltage	V _{IL}	-	-	4.5 to 5.5	-	-	0.8	-	0.8	-	0.8	V
High Level Output Voltage CMOS Loads	V _{OH}	V _{IH} or V _{IL}	-0.02	4.5	4.4	-	-	4.4	-	4.4	-	V
High Level Output Voltage TTL Loads			-4	4.5	3.98	-	-	3.84	-	3.7	-	V
Low Level Output Voltage CMOS Loads	V _{OL}	V _{IH} or V _{IL}	0.02	4.5	-	-	0.1	-	0.1	-	0.1	V
Low Level Output Voltage TTL Loads			4	4.5	-	-	0.26	-	0.33	-	0.4	V
Input Leakage Current	lı	V _{CC} and GND	0	5.5	-	-	±0.1	-	±1	-	±1	μA
Quiescent Device Current	Icc	V _{CC} or GND	0	5.5	-	-	8	-	80	-	160	μA
Additional Quiescent Device Current Per Input Pin: 1 Unit Load	∆I _{CC} (Note 2)	V _{CC} -2.1	-	4.5 to 5.5	-	100	360	-	450	-	490	μA

NOTE:

2. For dual-supply systems theoretical worst case (V_I = 2.4V, V_{CC} = 5.5V) specification is 1.8mA.

HCT Input Loading Table

INPUT	UNIT LOADS (NOTE)
P0-P7	0.20
TE, MR	0.40
CP	0.60
PE	0.80
PL	1.35

NOTE: Unit Load is ΔI_{CC} limit specified in DC Electrical Table, e.g., $360\mu A$ max at $25^{\circ}C$.

Prerequisite for Switching Specifications

		25 ⁰ C			-40 ⁰ C T	О 85 ⁰ С	-55 ⁰ C T						
SYMBOL	V _{CC} (V)	MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS				
HC TYPES													
t _W	2	165	-	-	205	-	250	-	ns				
	4.5	33	-	-	41	-	50	-	ns				
	6	28	-	-	35	-	43	-	ns				
t _W	2	125	-	-	155	-	190	-	ns				
	4.5	25	-	-	31	-	38	-	ns				
	6	21	-	-	26	-	32	-	ns				
	tw	t _W 2 4.5 6 t _W 2 4.5	t _W 2 165 4.5 33 6 28 t _W 2 125 4.5 25	$\begin{array}{ c c c c c c c } \mbox{SYMBOL} & \mbox{V}_{CC} (\mbox{V}) & \mbox{MIN} & \mbox{TYP} \\ \hline \\ & t_W & 2 & 165 & - \\ \hline & 4.5 & 33 & - \\ \hline & 6 & 28 & - \\ \hline & 6 & 28 & - \\ \hline & t_W & 2 & 125 & - \\ \hline & 4.5 & 25 & - \\ \hline \end{array}$	$\begin{array}{ c c c c c c c c c } \mbox{SYMBOL} & V_{CC} (V) & \mbox{MIN} & \mbox{TYP} & \mbox{MAX} \\ \hline \\ t_W & 2 & 165 & - & - \\ \hline 4.5 & 33 & - & - \\ \hline 6 & 28 & - & - \\ \hline 6 & 28 & - & - \\ \hline t_W & 2 & 125 & - & - \\ \hline 4.5 & 25 & - & - \\ \hline \end{array}$	$\begin{array}{ c c c c c c c c c } \mbox{SYMBOL} & \mbox{V}_{CC} (\mbox{V}) & \mbox{MIN} & \mbox{TYP} & \mbox{MAX} & \mbox{MIN} \\ \hline \\ t_W & 2 & 165 & - & - & 205 \\ \hline 4.5 & 33 & - & - & 41 \\ \hline 6 & 28 & - & - & 35 \\ \hline t_W & 2 & 125 & - & - & 155 \\ \hline 4.5 & 25 & - & - & 31 \\ \hline \end{array}$	$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	$\begin{array}{ c c c c c c c c c c c c c c c c c c c$	$\begin{array}{ c c c c c c c c c c c c c c c c c c c$				

				25 ⁰ C		-40°C 1	TO 85 ⁰ C	-55°C T	O 125 ⁰ C	
PARAMETER	SYMBOL	V _{CC} (V)	MIN	ТҮР	МАХ	MIN	МАХ	MIN	МАХ	
MR Pulse Width	t _W	2	125	-	-	135	-	190	-	ns
		4.5	25	-	-	31	-	38	-	ns
		6	21	-	-	26	-	32	-	ns
CP Max. Frequency	f _{CP(MAX)}	2	3	-	-	2	-	2	-	MHz
(Note 3)		4.5	15	-	-	12	-	10	-	MHz
		6	18	-	-	14	-	12	-	MHz
P to CP Set-up Time	ts∪	2	100	-	-	125	-	150	-	ns
		4.5	20	-	-	25	-	30	-	ns
		6	17	-	-	21	-	26	-	ns
PE to CP Set-up Time	ts∪	2	75	-	-	95	-	110	-	ns
		4.5	15	-	-	19	-	22	-	ns
		6	13	-	-	16	-	19	-	ns
TE to CP Set-up Time	t _{SU}	2	150	-	-	190	-	225	-	ns
		4.5	30	-	-	38	-	45	-	ns
		6	26	-	-	33	-	38	-	ns
P to CP Hold Time	tн	2	5	-	-	5	-	5	-	ns
		4.5	5	-	-	5	-	5	-	ns
		6	5	-	-	5	-	5	-	ns
TE to CP Hold Time	tн	2	0	-	-	0	-	0	-	ns
		4.5	0	-	-	0	-	0	-	ns
		6	0	-	-	0	-	0	-	ns
MR to CP Removal Time	t _{REM}	2	50	-	-	65	-	75	-	ns
		4.5	10	-	-	13	-	15	-	ns
		6	9	-	-	11	-	13	-	ns
PE to CP Hold Time	tH	2	2	-	-	2	-	2	-	ns
		4.5	2	-	-	2	-	2	-	ns
		6	2	-	-	2	-	2	-	ns
HCT TYPES		· · · · ·		•	I	•	•	•	•	
CP Pulse Width	t _W	4.5	35	-	-	44	-	53	-	ns
PL Pulse Width	t _W	4.5	43	-	-	54	-	65	-	ns
MR Pulse Width	t _W	4.5	35	-	-	44	-	53	-	ns
CP Max. Frequency (Note 3)	f _{CP(MAX)}	4.5	14	-	-	11	-	9	-	MHz
P to CP Set-up Time	t _{SU}	4.5	24	-	-	30	-	36	-	ns
PE to CP Set-up Time	ts∪	4.5	20	-	-	25	-	30	-	ns
TE to CP Set-up Time	t _{SU}	4.5	40	-	-	50	-	60	-	ns
P to CP Hold Time	t _Н	4.5	5	-	-	5	-	5	-	ns
TE to CP Hold Time	tн	4.5	0	-	-	0	-	0	-	ns
MR to CP Removal Time	t _{REM}	4.5	10	-	-	13	-	15	-	ns
PE to CP Hold Time	tH	4.5	2	-	-	2	-	2	-	ns

- Cwitching Crossifie - - -

Switching Specifications Input tr, tf = 6ns

		TEST	V _{CC}		25 ⁰ C			С ТО °С		C TO 5°C	
PARAMETER	SYMBOL	CONDITIONS	vcc (V)	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNITS
HC TYPES	-			-	-		-	-		-	-
Propagation Delay	t _{PLH,}	$C_L = 50 pF$	2	-	-	300	-	375	-	450	ns
CP to any $\overline{\text{TC}}$ (Async Preset)	^t PHL	$C_L = 50 pF$	4.5	-	-	60	-	75	-	90	ns
		C _L = 15pF	5	-	25	-	-		-		ns
		$C_L = 50 pF$	6	-	-	51	-	64	-	77	ns
CP to \overline{TC} (Sync Preset)	t _{PLH,}	$C_L = 50 pF$	2	-	-	300	-	375	-	450	ns
	^t PHL	$C_L = 50 pF$	4.5	-	-	60	-	75	-	90	ns
		C _L = 15pF	5	-	25	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	51	-	64	-	77	ns
TE to TC	t _{PLH,}	C _L = 50pF	2	-	-	200	-	250	-	300	ns
	tPHL	C _L = 50pF	4.5	-	-	40	-	50	-	60	ns
		C _L = 15pF	5	-	17	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	34	-	43	-	51	ns
PL to TC	^t PLH,	$C_L = 50 pF$	2	-	-	275	-	345	-	415	ns
	t _{PHL}	C _L = 50pF	4.5	-	-	55	-	69	-	83	ns
		C _L = 15pF	5	-	23	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	47	-	59	-	71	ns
MR to TC	t _{PLH,}	C _L = 50pF	2	-	-	275	-	345	-	415	ns
	^t PHL	C _L = 50pF	4.5	-	-	55	-	69	-	83	ns
		C _L = 15pF	5	-	23	-	-	-	-	-	ns
		C _L = 50pF	6	-	-	47	-	59	-	71	ns
Output Transition Time	t _{TLH} , t _{THL}	C _L = 50pF	2	-	-	75	-	95	-	110	ns
		C _L = 50pF	4.5	-	-	15	-	19	-	22	ns
		C _L = 50pF	6	-	-	13	-	16	-	19	ns
Input Capacitance	CI	C _L = 50pF	-	-	-	10	-	10	-	10	pF
CP Maximum Frequency	f _{MAX}	C _L = 15pF	5	-	25	-	-	-	-	-	MHz
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5	-	25	-	-	-	-	-	pF
HCT TYPES											
Propagation Delay		•									
CP to \overline{TC} (Async Preset)	^t PLH, t _{PHL}	$C_L = 50 pF$	4.5	-	-	60	-	75	-	90	ns
		C _L = 15pF	5	-	25	-	-	-	-	-	ns
\overline{CE} to \overline{TC} (Sync Preset)	t _{PLH,} t _{PHL}	$C_L = 50 pF$	4.5	-	-	63	-	79	-	95	ns
		C _L = 15pF	5	-	26	-	-	-	-	-	ns
TE to TC	t _{PLH,} t _{PHL}	C _L = 50pF	4.5	-	-	50	-	63	-	75	ns
		C _L = 15pF	5	-	21	-	-	-	-	-	ns
PL to TC	t _{PLH,}	C _L = 50pF	4.5	-	-	68	-	85	-	102	ns
	^t PHL	C _L = 15pF	5	-	28	-	-	-	-	-	ns

		TEST	V _{CC} (V)	25 ⁰ C			-40 ^o C TO 85 ^o C		-55 ⁰ C TO 125 ⁰ C		
PARAMETER	SYMBOL	CONDITIONS		MIN	ТҮР	MAX	MIN	MAX	MIN	MAX	UNITS
MR to TC	^t PLH,	$C_L = 50 pF$	4.5	-	-	55	-	69	-	83	ns
	^t PHL	C _L = 15pF	5	-	23	-	-	-	-	-	ns
Output Transition Time	t _{THL} , t _{TLH}	$C_L = 50 pF$	4.5	-	-	15	-	19	-	22	ns
Input Capacitance	C _{IN}	$C_L = 50 pF$	-	-	-	10	-	10	-	10	pF
CP Maximum Frequency	f _{MAX}	C _L = 15pF	5	-	25	-	-	-	-	-	MHz
Power Dissipation Capacitance (Notes 4, 5)	C _{PD}	-	5	-	27	-	-	-	-	-	pF

Switching Specifications Input t_r , $t_f = 6ns$ (Continued)

NOTES:

 Noncascaded operation only. With cascaded counters clock-to-terminal count propagation delays, count enables (PE or TE)-to-clock SET UP TIMES, and count enables (PE or TE)-to-clock HOLD TIMES determine maximum clock frequency. For example, with these HC devices:

 $C_{P} f_{MAX} = \frac{1}{CP \text{-to-}\overline{TC} \text{ prop delay + }\overline{TE}\text{-to-}CP \text{ Setup Time + }\overline{TE}\text{-to-}CP \text{ Hold Time}} = \frac{1}{60 + 30 + 0} \approx 11 \text{ MHz}$

4. C_{PD} is used to determine the dynamic power consumption, per package.

5. $P_D = V_{CC}^2 f_i + C_L V_{CC}^2 f_o$ where f_i = Input Frequency, C_L = Output Load Capacitance, V_{CC} = Supply Voltage, f_o = Output Frequency.

Timing Diagrams

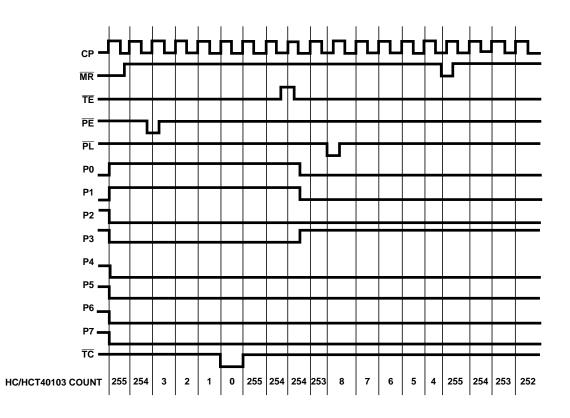


FIGURE 1.

Test Circuits and Waveforms tr INPUT LEVEL INPUT LEVEL CP ٧s ٧s MR GND GND tw 1/f_{MAX} tPHL t_{PLH} TC 10% t_{REM} – 'e INPUT LEVEL 90% СР GND t_{THL} t_{TLH} FIGURE 2. FIGURE 3. tf tf INPUT LEVEL INPUT LEVEL MR 10% GND TE 6 90% tPHL tsu t_{PLH} 10% - INPUT LEVEL ٧s TC 90% CP GND t_{THL} t_{TLH} FIGURE 4. FIGURE 5. VALID INPUT LEVEL INPUTS ٧s GND P0 - P7 TE OR PE INPUT LEVEL ٧٩ th GND tsu INPUT LEVEL PE tsu ٧s INPUT LEVEL GND CP ٧s GND t_h tsu t_{REC} INPUT LEVEL СР ٧s GND FIGURE 7. FIGURE 6. $t_{WL} + t_{WH} = \frac{1}{fC_L}$ fC_L $t_r C_L = 6ns$ twL + twH = t_fC_L = 6ns ∙t_fCL trCL -Vcc 3V 90% 2.7 CLOCK CLOCK 50% 1.3V 50% 50% 1.3V 3V -10% -0.3V 10% 0.3V GND GND twн twн twi twi NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%. NOTE: Outputs should be switching from 10% V_{CC} to 90% V_{CC} in accordance with device truth table. For f_{MAX} , input duty cycle = 50%. FIGURE 9. HCT CLOCK PULSE RISE AND FALL TIMES AND FIGURE 8. HC CLOCK PULSE RISE AND FALL TIMES AND PULSE WIDTH PULSE WIDTH



24-Aug-2014

PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Device Marking	Samples
5962-9055301EA	(1) ACTIVE	CDIP	J	16	1	(2) TBD	(6) A42	(3) N / A for Pkg Type	-55 to 125	(4/5) 5962-9055301EA CD54HC40103F3A	Samples
5HC40103F3AS228	OBSOLETE	CDIP	J	16		TBD	Call TI	Call TI	-55 to 125		
CD54HC40103F	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	CD54HC40103F	Samples
CD54HC40103F3A	ACTIVE	CDIP	J	16	1	TBD	A42	N / A for Pkg Type	-55 to 125	5962-9055301EA CD54HC40103F3A	Samples
CD74HC40103E	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC40103E	Samples
CD74HC40103EE4	ACTIVE	PDIP	N	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HC40103E	Samples
CD74HC40103M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC40103M	Samples
CD74HC40103M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC40103M	Samples
CD74HC40103M96E4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC40103M	Samples
CD74HC40103M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC40103M	Samples
CD74HC40103ME4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC40103M	Samples
CD74HC40103MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC40103M	Samples
CD74HC40103MT	ACTIVE	SOIC	D	16	250	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HC40103M	Samples
CD74HCT40103E	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT40103E	Samples
CD74HCT40103EE4	ACTIVE	PDIP	Ν	16	25	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	-55 to 125	CD74HCT40103E	Samples
CD74HCT40103M	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT40103M	Samples
CD74HCT40103M96	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT40103M	Samples



24-Aug-2014

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish (6)	MSL Peak Temp	Op Temp (°C)	Device Marking (4/5)	Samples
CD74HCT40103M96G4	ACTIVE	SOIC	D	16	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT40103M	Samples
CD74HCT40103MG4	ACTIVE	SOIC	D	16	40	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-55 to 125	HCT40103M	Samples

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. - The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.

(5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.

⁽⁶⁾ Lead/Ball Finish - Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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OTHER QUALIFIED VERSIONS OF CD54HC40103, CD74HC40103 :

- Catalog: CD74HC40103
- Automotive: CD74HC40103-Q1, CD74HC40103-Q1
- Enhanced Product: CD74HC40103-EP, CD74HC40103-EP
- Military: CD54HC40103

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Automotive Q100 devices qualified for high-reliability automotive applications targeting zero defects
- Enhanced Product Supports Defense, Aerospace and Medical Applications
- Military QML certified for Military and Defense Applications

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TAPE AND REEL INFORMATION





QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



1	All dimensions are nominal												
	Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
	CD74HC40103M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1
	CD74HCT40103M96	SOIC	D	16	2500	330.0	16.4	6.5	10.3	2.1	8.0	16.0	Q1



PACKAGE MATERIALS INFORMATION

19-Mar-2008



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
CD74HC40103M96	SOIC	D	16	2500	333.2	345.9	28.6
CD74HCT40103M96	SOIC	D	16	2500	333.2	345.9	28.6

J (R-GDIP-T**) 14 LEADS SHOWN

CERAMIC DUAL IN-LINE PACKAGE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. This package is hermetically sealed with a ceramic lid using glass frit.
- D. Index point is provided on cap for terminal identification only on press ceramic glass frit seal only.
- E. Falls within MIL STD 1835 GDIP1-T14, GDIP1-T16, GDIP1-T18 and GDIP1-T20.

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- \triangle The 20 pin end lead shoulder width is a vendor option, either half or full width.



D (R-PDSO-G16)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AC.



4211283-4/E 08/12

D (R-PDSO-G16) PLASTIC SMALL OUTLINE Stencil Openings (Note D) Example Board Layout (Note C) –16x0,55 -14x1,27 -14x1,27 16x1,50 5,40 5.40 Example Non Soldermask Defined Pad Example Pad Geometry (See Note C) 0,60 .55 Example 1. Solder Mask Opening (See Note E) -0,07 All Around

NOTES: A. All linear dimensions are in millimeters.

- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
 E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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